Schottky Barrier Diode

DB3X501K0L

Unit: mm

# **Panasonic**

## DB3X501K0L

## Silicon epitaxial planar type

For high speed switching circuits DB2J501 in Mini3 type package

#### ■ Features

- · Short reverse recovery time trr
- Low terminal capacitance Ct
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol:4H

#### ■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

2. 9

0. 4

0. 16

1. Anode
2. N.C
3. Cathode

Panasonic Mini3-G3-B

JEITA SC-59A

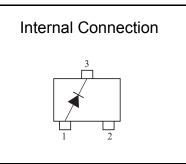
Code TO-236AA/SOT-23

	Code
,	

#### ■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Reverse voltage	VR	50	V
Repctitive peak reverse voltage	VRRM	50	V
Peak forward current	IFM	300	mA
Forward current (Average)	IF(AV)	200	mA
Non-repetitive peak forward surge current *1	IFSM	1	Α
Junction temperature	Tj	125	ç
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +125	°C

Note: \*1 50 Hz sine wave 1 cycle (Non-repetitive peak current)



Established: 2010-02-24 Revised: 2013-12-13 **Panasonic** 

Revision. 2

Schottky Barrier Diode

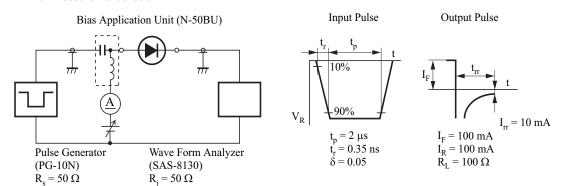
## DB3X501K0L

#### ■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF1	IF = 30 mA			0.36	V
- Tolward vollage	VF2	IF = 200 mA			0.55	V
Reverse current	IR	VR = 50 V			200	μA
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		4		pF
Reverse recovery time *1	trr	IF = IR = 100 mA, Irr = 10 mA, RL = 100 $\Omega$		1.6		ns

Note: 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

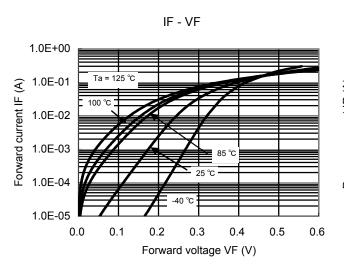
- 2. Schottky diode is frail with static electricity, and it should be kept in safety from shock of static electricity and static electricity level.
- 3. Absolute frequency of input and output is 1 000 MHz.
- 4. \*1 : trr measurement circuit

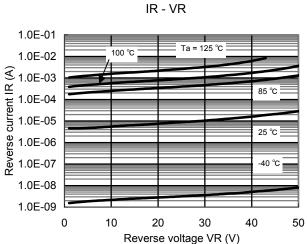


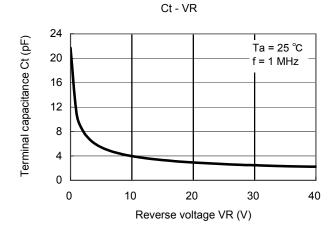
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Schottky Barrier Diode DB3X501K0L

## Technical Data (reference)







Established: 2010-02-24 Revised: 2013-12-13

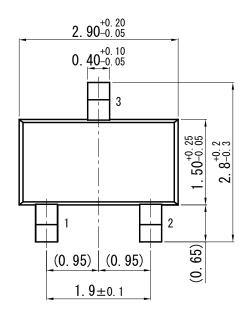
Schottky Barrier Diode

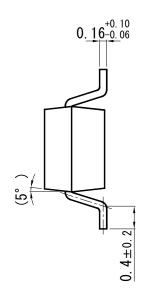
DB3X501K0L

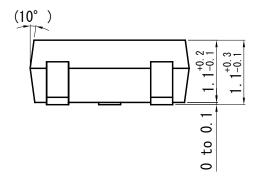
Unit: mm

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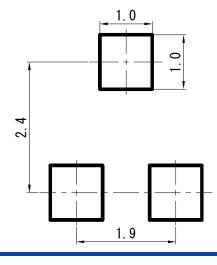
Mini3-G3-B







■ Land Pattern (Reference) (Unit: mm)



Established: 2010-02-24 Revised: 2013-12-13

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